
2SC4680

Silicon NPN Epitaxial

HITACHI

ADE-208-1118A (Z)
2nd. Edition
Mar. 2001

Application

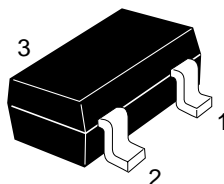
VHF / UHF high frequency switching

Features

- Low R_{on} and high performance for RF switch.
- Capable of high density mounting.

Outline

MPAK



- 1. Emitter
- 2. Base
- 3. Collector

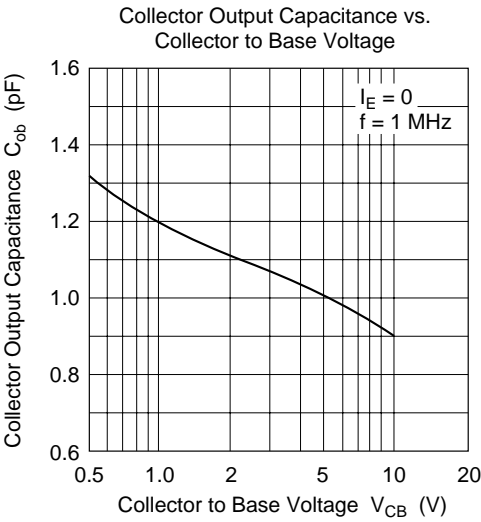
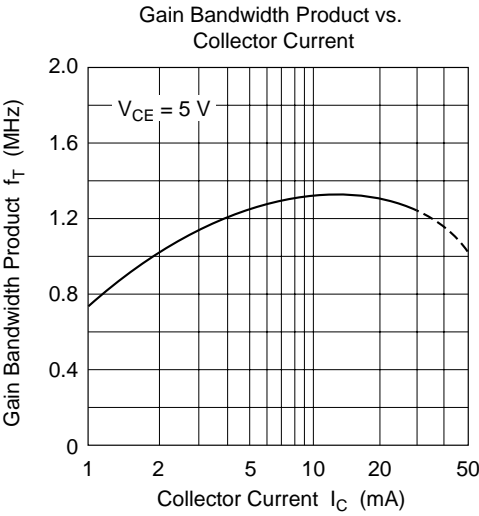
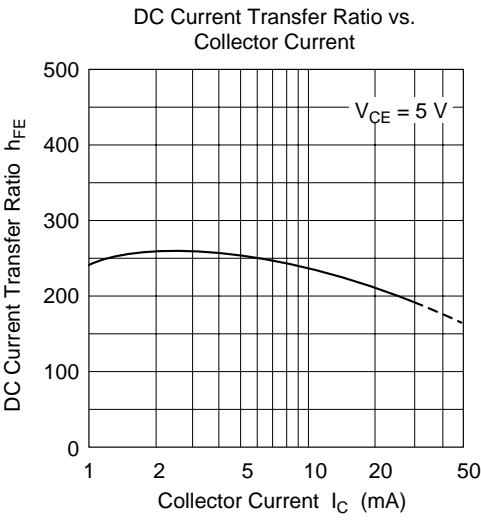
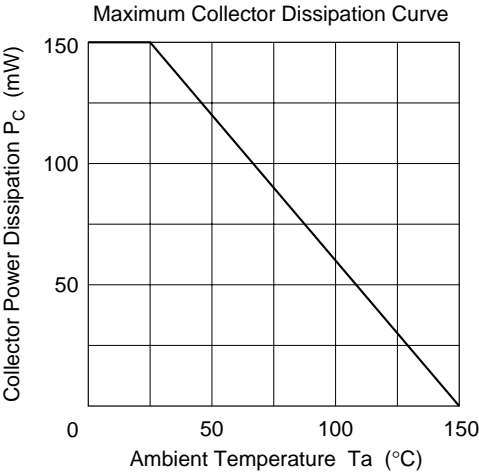
Note: Marking is "XU—".

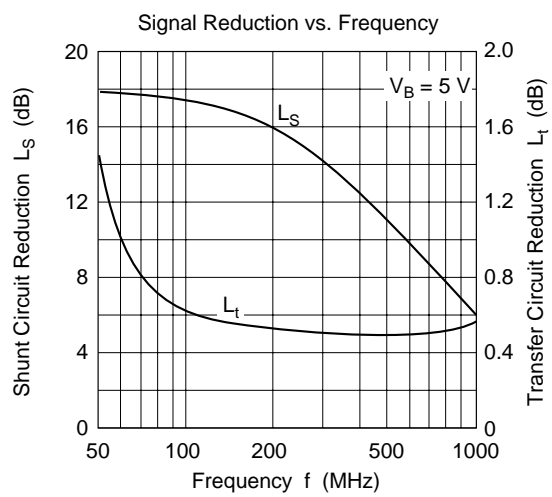
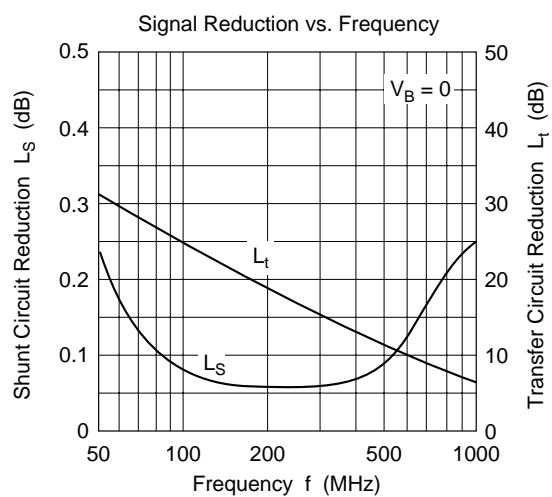
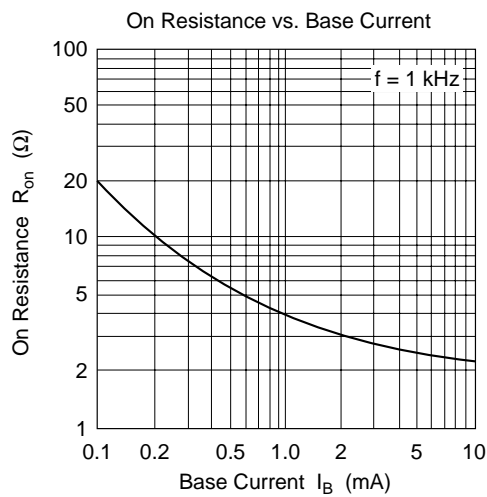
Absolute Maximum Ratings ($T_a = 25^{\circ}\text{C}$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	12	V
Collector to emitter voltage	V_{CEO}	8	V
Emitter to base voltage	V_{EBO}	3	V
Collector current	I_{C}	50	mA
Collector power dissipation	P_{C}	150	mW
Junction temperature	T_{j}	150	$^{\circ}\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^{\circ}\text{C}$

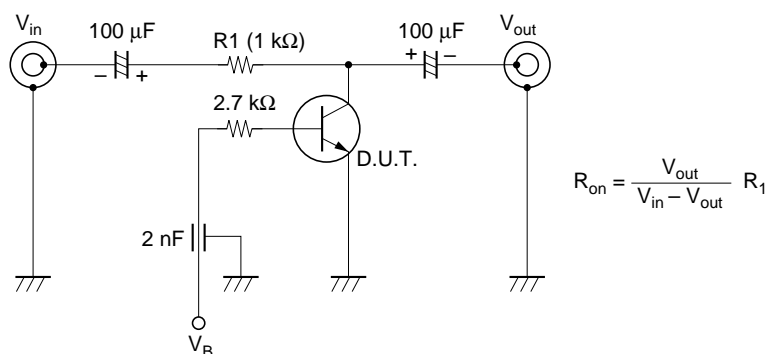
Electrical Characteristics ($T_a = 25^{\circ}\text{C}$)

Item	Symbol	Min	Typ	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	12	—	—	V	$I_{\text{C}} = 10\text{ }\mu\text{A}$, $I_{\text{E}} = 0$
Collector cutoff current	I_{CBO}	—	—	10	μA	$V_{\text{CB}} = 12\text{ V}$, $I_{\text{E}} = 0$
	I_{CEO}	—	—	1	mA	$V_{\text{CE}} = 8\text{ V}$, $R_{\text{BE}} = \infty$
Emitter cutoff current	I_{EBO}	—	—	10	μA	$V_{\text{EB}} = 3\text{ V}$, $I_{\text{C}} = 0$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	70	100	mV	$I_{\text{C}} = 20\text{ mA}$, $I_{\text{B}} = 4\text{ mA}$
DC current transfer ratio	h_{FE}	100	250	—		$V_{\text{CE}} = 5\text{ V}$, $I_{\text{C}} = 5\text{ mA}$
Collector output capacitance	C_{ob}	—	1.0	1.5	pF	$V_{\text{CB}} = 5\text{ V}$, $I_{\text{E}} = 0$, $f = 1\text{ MHz}$

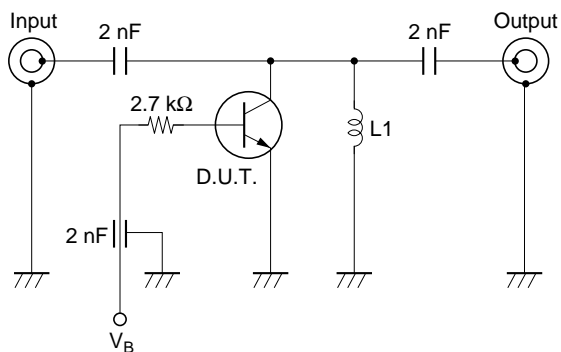




On Resistance Test Circuit

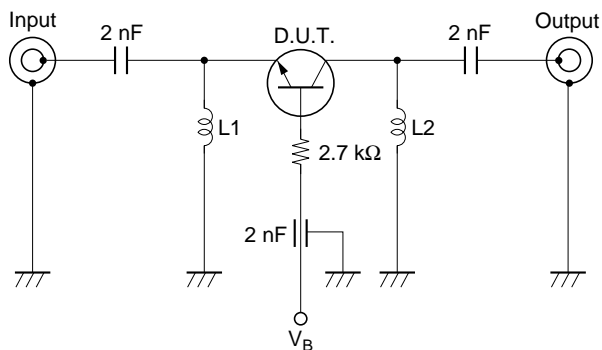


Reduction Test Circuit (Shunt Circuit)



L_1 : 3 mm inside dia, $\phi 0.2$ mm enameled copper wire, 15 turns

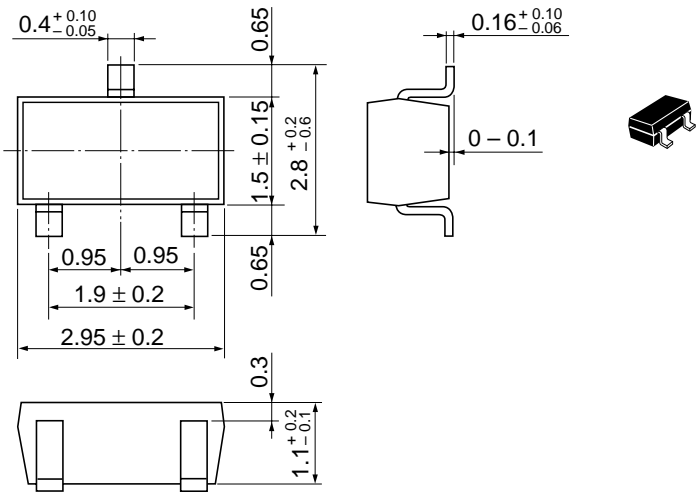
Reduction Test Circuit (Transfer Circuit)



L_1, L_2 : 3 mm inside dia, $\phi 0.2$ mm enameled copper wire, 15 turns

Package Dimensions

As of January, 2001
Unit: mm



Hitachi Code	MPAK
JEDEC	—
EIAJ	Conforms
Mass (reference value)	0.011 g

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